Device Marking FQA9N90C		Device Packag		e R	eel Size	Тар	e Widt	h	Quan	tity
		FQA9N90C	TO-3P						30	
FQA9N90C		FQA9N90C_F109	TO-3PN						30	
Electric	al Cha	racteristics T _c .	= 25°C unless othe	rwise noted		·				
Symbol		Parameter		Test	Conditio	ns	Min	Тур	Max	Units
Off Charac	teristics			•						
BV _{DSS}	Drain-Sou	urce Breakdown Voltag	je	V _{GS} = 0 V, I _E	, = 250 μA		900			V
∆BV _{DSS} / ∆T _J	Breakdov	akdown Voltage Temperature Coefficient		I_D = 250 µA, Referenced to 25°C			0.99		V/°C	
I _{DSS}	Zero Gate Voltage Drain Current		V _{DS} = 900 V, V _{GS} = 0 V				10	μA		
				V _{DS} = 720 V	T _C = 125°C				100	μA
I _{GSSF}	Gate-Bod	dy Leakage Current, Forward		V _{GS} = 30 V,	V_{GS} = 30 V, V_{DS} = 0 V				100	nA
I _{GSSR}	Gate-Body Leakage Current, Reverse		V_{GS} = -30 V, V_{DS} = 0 V				-100	nA		
On Charact	eristics									1
V _{GS(th)}	Gate Thre	ate Threshold Voltage		V_{DS} = V_{GS} , I_D = 250 μ A		3.0		5.0	V	
R _{DS(on)}	Static Dra	Drain-Source On-Resistance		V _{GS} = 10 V, I _D = 4.5 A			1.12	1.4	Ω	
9 _{FS}	Forward 7	vard Transconductance		$V_{DS} = 50 \text{ V}, I_D = 4.5 \text{ A}$ (Note 4)			9.2		S	
Dynamic Ch	naracteristi	CS		1				1	1	1
C _{iss}	Input Cap	t Capacitance out Capacitance		V _{DS} = 25 V, V _{GS} = 0 V, f = 1.0 MHz			2100	2730	pF	
C _{oss}	Output Ca						175	230	pF	
C _{rss}		Transfer Capacitance						14	18	pF
Switching C	1							1	1	
t _{d(on)}	Turn-On I	on Delay Time		V_{DD} = 450 V, I _D = 11.0A, R _G = 25 Ω			50	110	ns	
t _r	Turn-On I						120	250	ns	
t _{d(off)}	Turn-Off I	Delay Time					100	210	ns	
t _f	Turn-Off I	Fall Time		1		(Note 4, 5)		75	160	ns
Qg	Total Gate	e Charge		V _{DS} = 720 V, I _D = 11.0A, V _{GS} = 10 V				45	58	nC
Q _{gs}	Gate-Sou	Irce Charge				·		13		nC
Q _{gd}	Gate-Dra	in Charge				(Note 4, 5)		18		nC
	e Diode C	haracteristics and Max	imum Ratings	I				1	1	1
I _S	Maximum	n Continuous Drain-So	urce Diode For	rward Current					9.0	Α
I _{SM}	Maximum	Aximum Pulsed Drain-Source Diode Forward		d Current					36	Α
V _{SD}	Drain-Sou	urce Diode Forward Vo	ltage	V _{GS} = 0 V, I _S	=9.0 A				1.4	V
t _{rr}	Reverse	Recovery Time			V _{GS} = 0 V, I _S = 9.0 A,			550		ns
Q _{rr}	Reverse	Recovery Charge		dI _F / dt = 100 A/μs		(Note 4)		6.5		μC

1. Repetitive Rating : Pulse width limited by maximum junction temperature

2. L = 21mH, I_{AS} =9.0A, V_{DD} = 50V, R_G = 25 Ω , Starting T_J = 25°C

3. I_{SD} \leq 9.0A, di/dt \leq 200A/µs, V_{DD} \leq BV_{DSS,} Starting ~T_J = 25°C

4. Pulse Test : Pulse width $\leq 300 \mu s,$ Duty cycle $\leq 2\%$

5. Essentially independent of operating temperature

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-55°C

6

0.8

V_{DS} = 180V

V_{DS} = 450V

V_{DS} = 720V

20

30

Notes : 1. V_{DS} = 50V 2. 250µ s Pulse Test

Notes : 1. V_{cs} = 0V 2. 250µ s Pulse

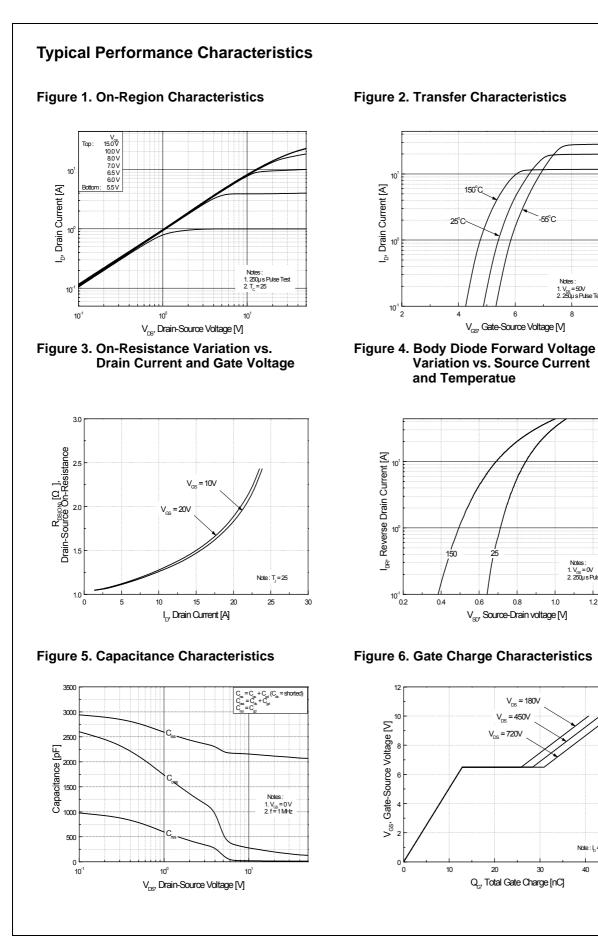
1.2

1.4

1.0

10

8

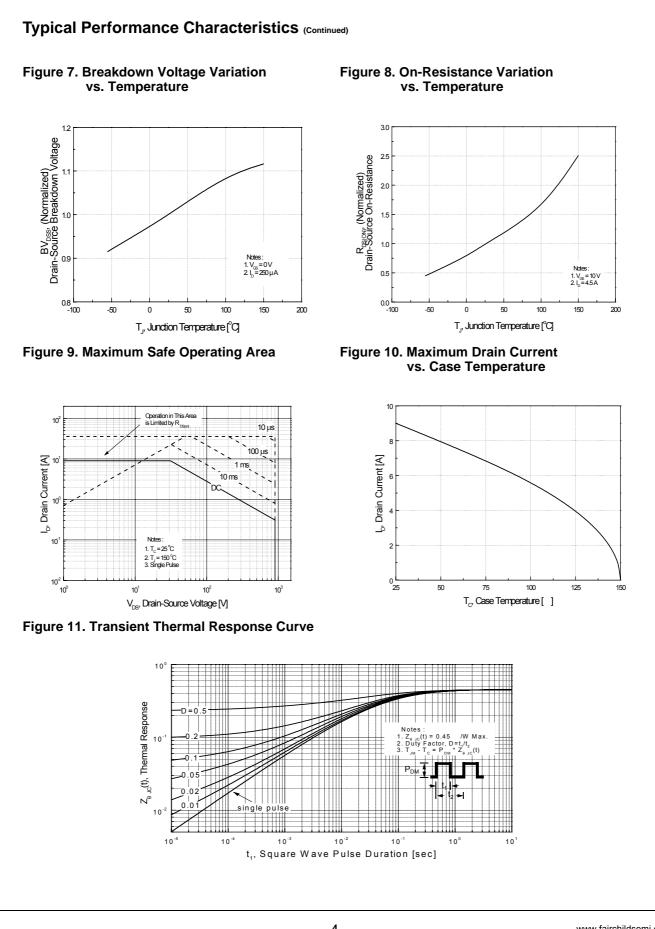


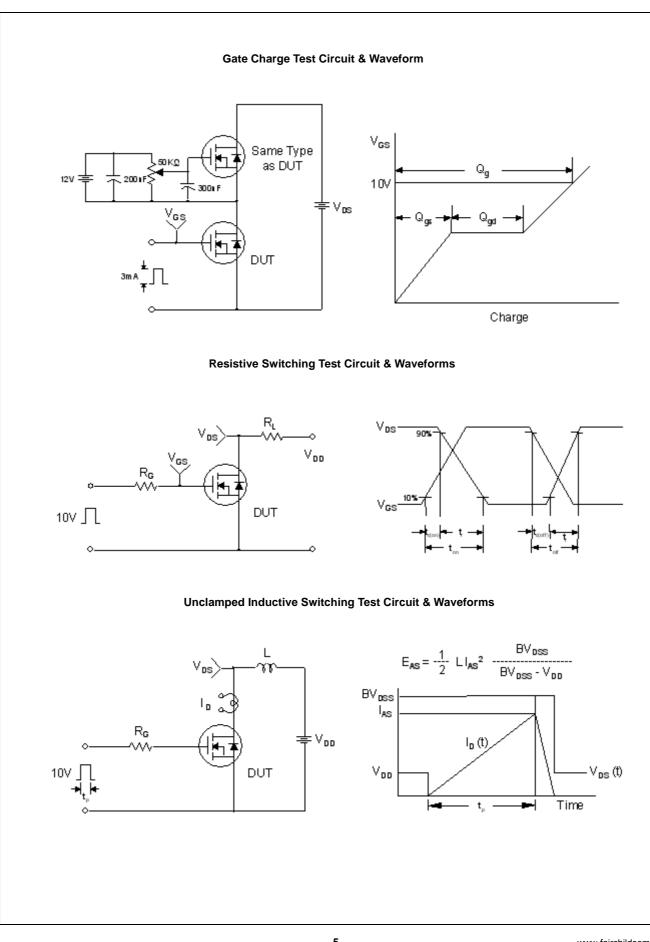
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50

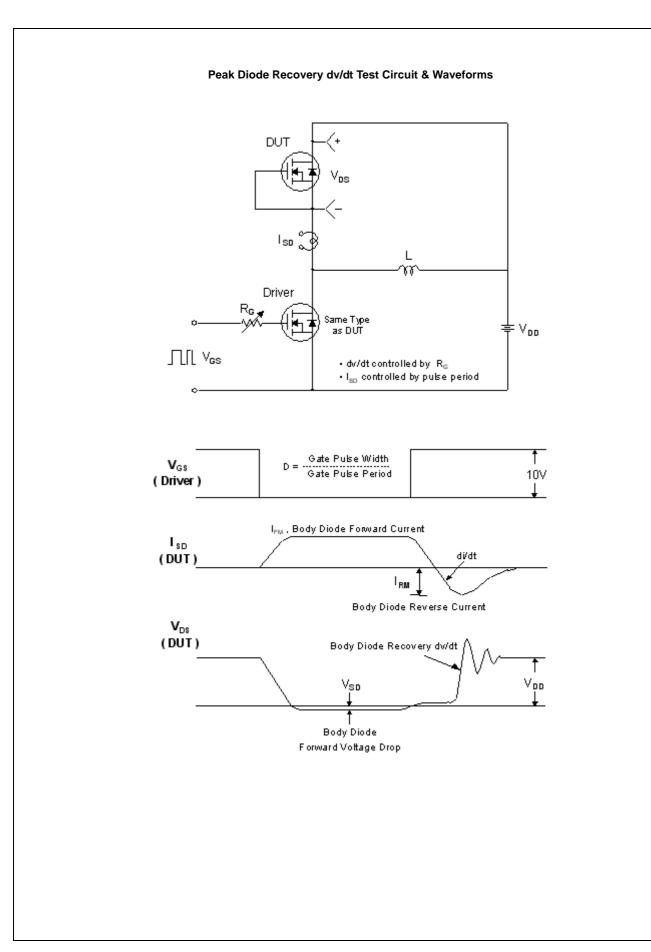
Note: In = 9A

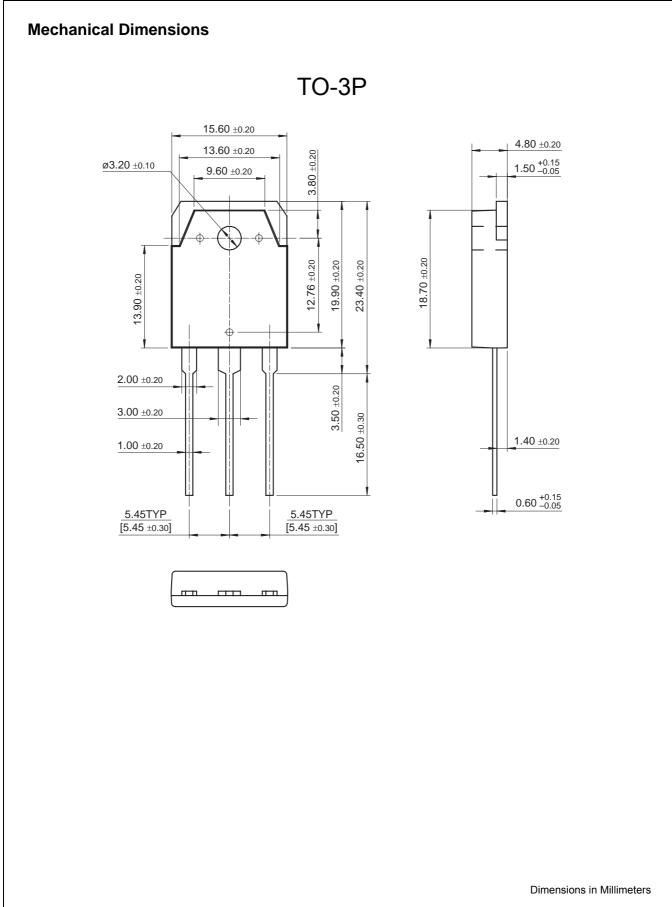
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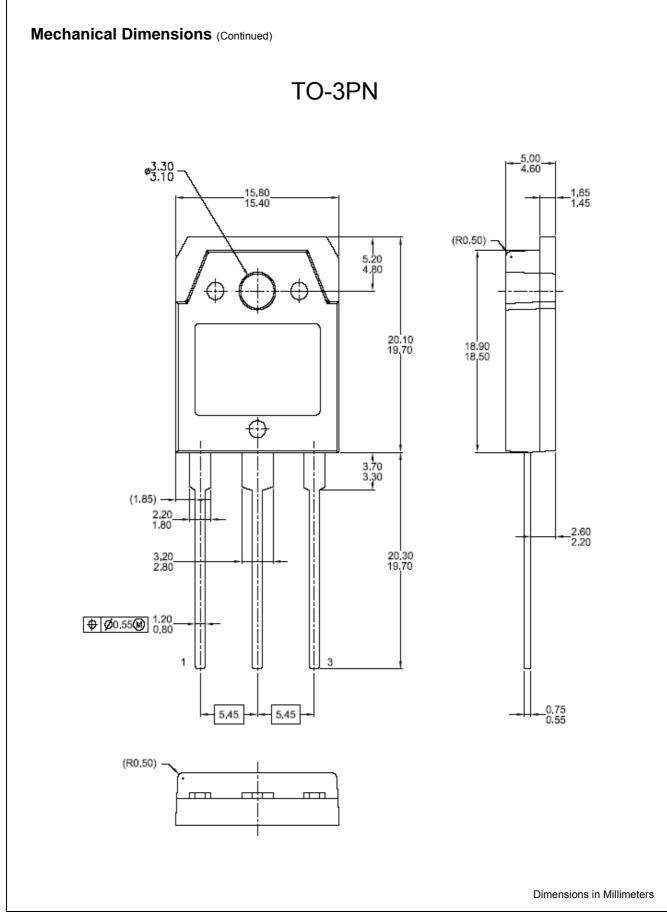


FQA9N90C Rev. A





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Rev. 129